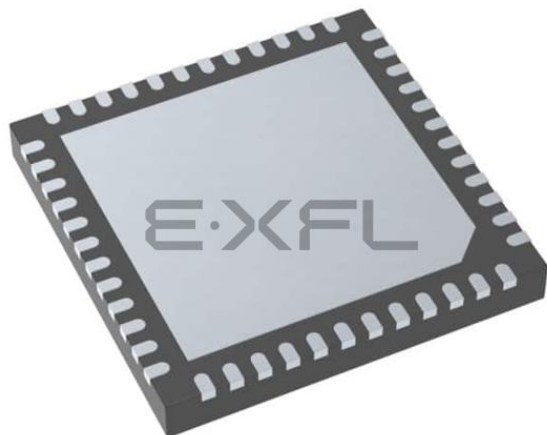




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Details

Product Status	Active
Core Processor	ARM® Cortex®-M0
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, HDMI-CEC, I²C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, I²S, POR, PWM, WDT
Number of I/O	37
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	16K x 8
Voltage - Supply (Vcc/Vdd)	1.65V ~ 3.6V
Data Converters	A/D 10x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	48-UFQFN Exposed Pad
Supplier Device Package	48-UFQFPN (7x7)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f072cbu6tr

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2 Description

The STM32F072x8/xB microcontrollers incorporate the high-performance ARM® Cortex®-M0 32-bit RISC core operating at up to 48 MHz frequency, high-speed embedded memories (up to 128 Kbytes of Flash memory and 16 Kbytes of SRAM), and an extensive range of enhanced peripherals and I/Os. All devices offer standard communication interfaces (two I²Cs, two SPI/I²S, one HDMI CEC and four USARTs), one USB Full-speed device (crystal-less), one CAN, one 12-bit ADC, one 12-bit DAC with two channels, seven 16-bit timers, one 32-bit timer and an advanced-control PWM timer.

The STM32F072x8/xB microcontrollers operate in the -40 to +85 °C and -40 to +105 °C temperature ranges, from a 2.0 to 3.6 V power supply. A comprehensive set of power-saving modes allows the design of low-power applications.

The STM32F072x8/xB microcontrollers include devices in seven different packages ranging from 48 pins to 100 pins with a die form also available upon request. Depending on the device chosen, different sets of peripherals are included.

These features make the STM32F072x8/xB microcontrollers suitable for a wide range of applications such as application control and user interfaces, hand-held equipment, A/V receivers and digital TV, PC peripherals, gaming and GPS platforms, industrial applications, PLCs, inverters, printers, scanners, alarm systems, video intercoms and HVACs.

3.4 Cyclic redundancy check calculation unit (CRC)

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code using a configurable generator polynomial value and size.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a signature of the software during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.

3.5 Power management

3.5.1 Power supply schemes

- $V_{DD} = V_{DDIO1} = 2.0$ to 3.6 V: external power supply for I/Os (V_{DDIO1}) and the internal regulator. It is provided externally through VDD pins.
- V_{DDA} = from V_{DD} to 3.6 V: external analog power supply for ADC, DAC, Reset blocks, RCs and PLL (minimum voltage to be applied to V_{DDA} is 2.4 V when the ADC or DAC are used). It is provided externally through VDDA pin. The V_{DDA} voltage level must be always greater or equal to the V_{DD} voltage level and must be established first.
- $V_{DDIO2} = 1.65$ to 3.6 V: external power supply for marked I/Os. V_{DDIO2} is provided externally through the VDDIO2 pin. The V_{DDIO2} voltage level is completely independent from V_{DD} or V_{DDA} , but it must not be provided without a valid supply on V_{DD} . The V_{DDIO2} supply is monitored and compared with the internal reference voltage (V_{REFINT}). When the V_{DDIO2} is below this threshold, all the I/Os supplied from this rail are disabled by hardware. The output of this comparator is connected to EXTI line 31 and it can be used to generate an interrupt. Refer to the pinout diagrams or tables for concerned I/Os list.
- $V_{BAT} = 1.65$ to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when V_{DD} is not present.

For more details on how to connect power pins, refer to [Figure 13: Power supply scheme](#).

3.5.2 Power supply supervisors

The device has integrated power-on reset (POR) and power-down reset (PDR) circuits. They are always active, and ensure proper operation above a threshold of 2 V. The device remains in reset mode when the monitored supply voltage is below a specified threshold, $V_{POR/PDR}$, without the need for an external reset circuit.

- The POR monitors only the V_{DD} supply voltage. During the startup phase it is required that V_{DDA} should arrive first and be greater than or equal to V_{DD} .
- The PDR monitors both the V_{DD} and V_{DDA} supply voltages, however the V_{DDA} power supply supervisor can be disabled (by programming a dedicated Option bit) to reduce the power consumption if the application design ensures that V_{DDA} is higher than or equal to V_{DD} .

The device features an embedded programmable voltage detector (PVD) that monitors the V_{DD} power supply and compares it to the V_{PVD} threshold. An interrupt can be generated when V_{DD} drops below the V_{PVD} threshold and/or when V_{DD} is higher than the V_{PVD} .

threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

3.5.3 Voltage regulator

The regulator has two operating modes and it is always enabled after reset.

- Main (MR) is used in normal operating mode (Run).
- Low power (LPR) can be used in Stop mode where the power demand is reduced.

In Standby mode, it is put in power down mode. In this mode, the regulator output is in high impedance and the kernel circuitry is powered down, inducing zero consumption (but the contents of the registers and SRAM are lost).

3.5.4 Low-power modes

The STM32F072x8/xB microcontrollers support three low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- **Sleep mode**

In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

- **Stop mode**

Stop mode achieves very low power consumption while retaining the content of SRAM and registers. All clocks in the 1.8 V domain are stopped, the PLL, the HSI RC and the HSE crystal oscillators are disabled. The voltage regulator can also be put either in normal or in low power mode.

The device can be woken up from Stop mode by any of the EXTI lines. The EXTI line source can be one of the 16 external lines, the PVD output, RTC, I2C1, USART1, USART2, USB, COMPx, V_{DDIO2} supply comparator or the CEC.

The CEC, USART1, USART2 and I2C1 peripherals can be configured to enable the HSI RC oscillator so as to get clock for processing incoming data. If this is used when the voltage regulator is put in low power mode, the regulator is first switched to normal mode before the clock is provided to the given peripheral.

- **Standby mode**

The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.8 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, SRAM and register contents are lost except for registers in the RTC domain and Standby circuitry.

The device exits Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on the WKUP pins, or an RTC event occurs.

Note: The RTC, the IWDG, and the corresponding clock sources are not stopped by entering Stop or Standby mode.

3.6 Clocks and startup

System clock selection is performed on startup, however the internal RC 8 MHz oscillator is selected as default CPU clock on reset. An external 4-32 MHz clock can be selected, in which case it is monitored for failure. If failure is detected, the system automatically switches

Both comparators can wake up from STOP mode, generate interrupts and breaks for the timers and can be also combined into a window comparator.

3.13 Touch sensing controller (TSC)

The STM32F072x8/xB devices provide a simple solution for adding capacitive sensing functionality to any application. These devices offer up to 24 capacitive sensing channels distributed over 8 analog I/O groups.

Capacitive sensing technology is able to detect the presence of a finger near a sensor which is protected from direct touch by a dielectric (glass, plastic...). The capacitive variation introduced by the finger (or any conductive object) is measured using a proven implementation based on a surface charge transfer acquisition principle. It consists in charging the sensor capacitance and then transferring a part of the accumulated charges into a sampling capacitor until the voltage across this capacitor has reached a specific threshold. To limit the CPU bandwidth usage, this acquisition is directly managed by the hardware touch sensing controller and only requires few external components to operate. For operation, one capacitive sensing GPIO in each group is connected to an external capacitor and cannot be used as effective touch sensing channel.

The touch sensing controller is fully supported by the STMTouch touch sensing firmware library, which is free to use and allows touch sensing functionality to be implemented reliably in the end application.

Table 5. Capacitive sensing GPIOs available on STM32F072x8/xB devices

Group	Capacitive sensing signal name	Pin name	Group	Capacitive sensing signal name	Pin name
1	TSC_G1_IO1	PA0	5	TSC_G5_IO1	PB3
	TSC_G1_IO2	PA1		TSC_G5_IO2	PB4
	TSC_G1_IO3	PA2		TSC_G5_IO3	PB6
	TSC_G1_IO4	PA3		TSC_G5_IO4	PB7
2	TSC_G2_IO1	PA4	6	TSC_G6_IO1	PB11
	TSC_G2_IO2	PA5		TSC_G6_IO2	PB12
	TSC_G2_IO3	PA6		TSC_G6_IO3	PB13
	TSC_G2_IO4	PA7		TSC_G6_IO4	PB14
3	TSC_G3_IO1	PC5	7	TSC_G7_IO1	PE2
	TSC_G3_IO2	PB0		TSC_G7_IO2	PE3
	TSC_G3_IO3	PB1		TSC_G7_IO3	PE4
	TSC_G3_IO4	PB2		TSC_G7_IO4	PE5
4	TSC_G4_IO1	PA9	8	TSC_G8_IO1	PD12
	TSC_G4_IO2	PA10		TSC_G8_IO2	PD13
	TSC_G4_IO3	PA11		TSC_G8_IO3	PD14
	TSC_G4_IO4	PA12		TSC_G8_IO4	PD15

Figure 5. UFBGA64 package pinout

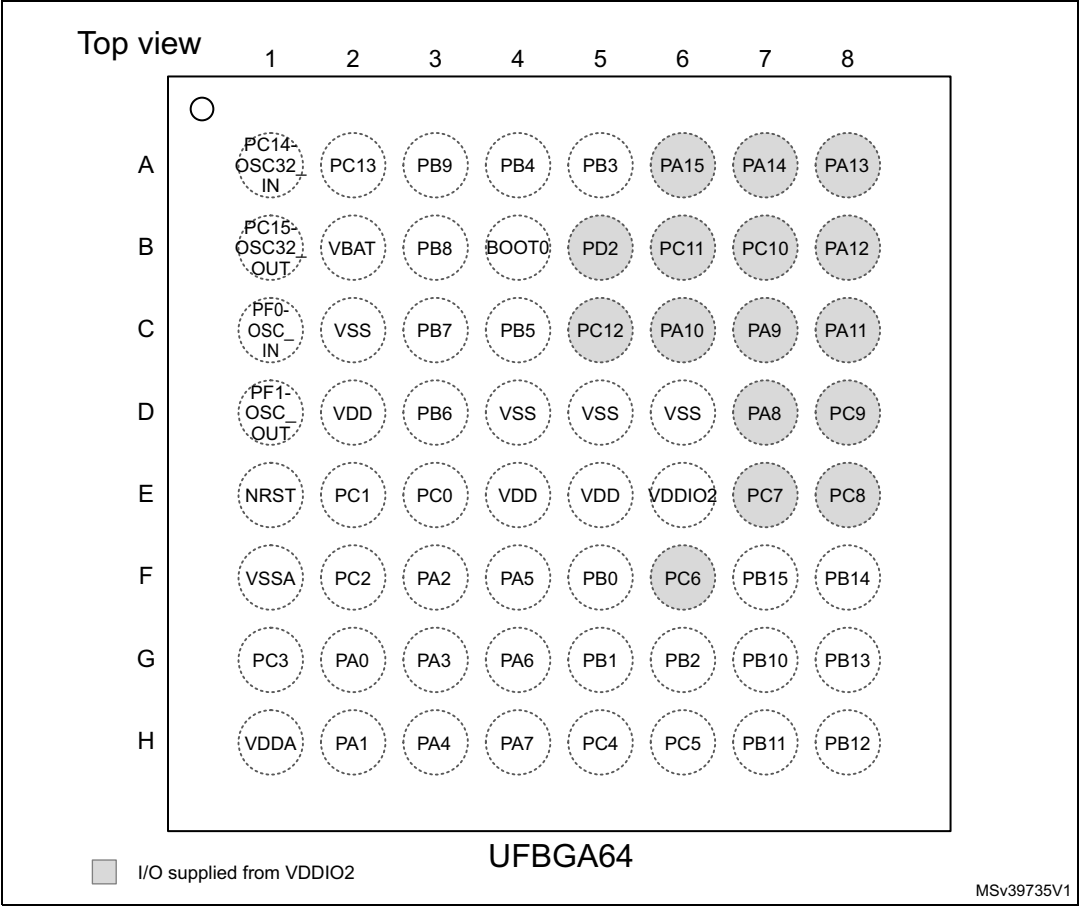


Figure 8. UFQFPN48 package pinout

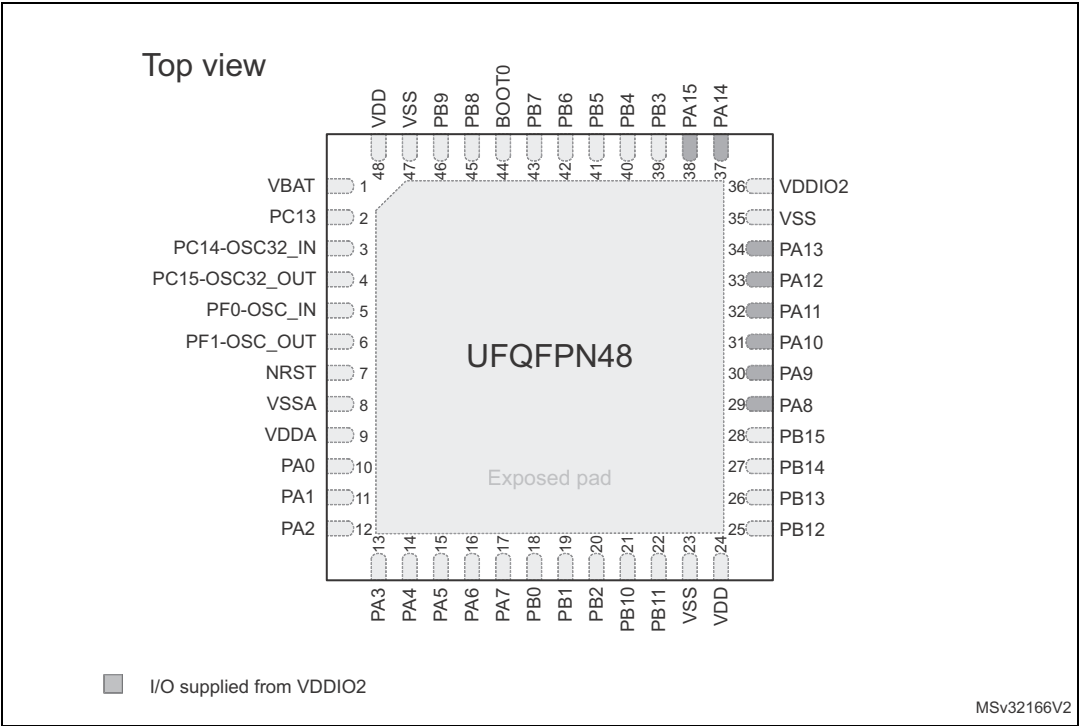
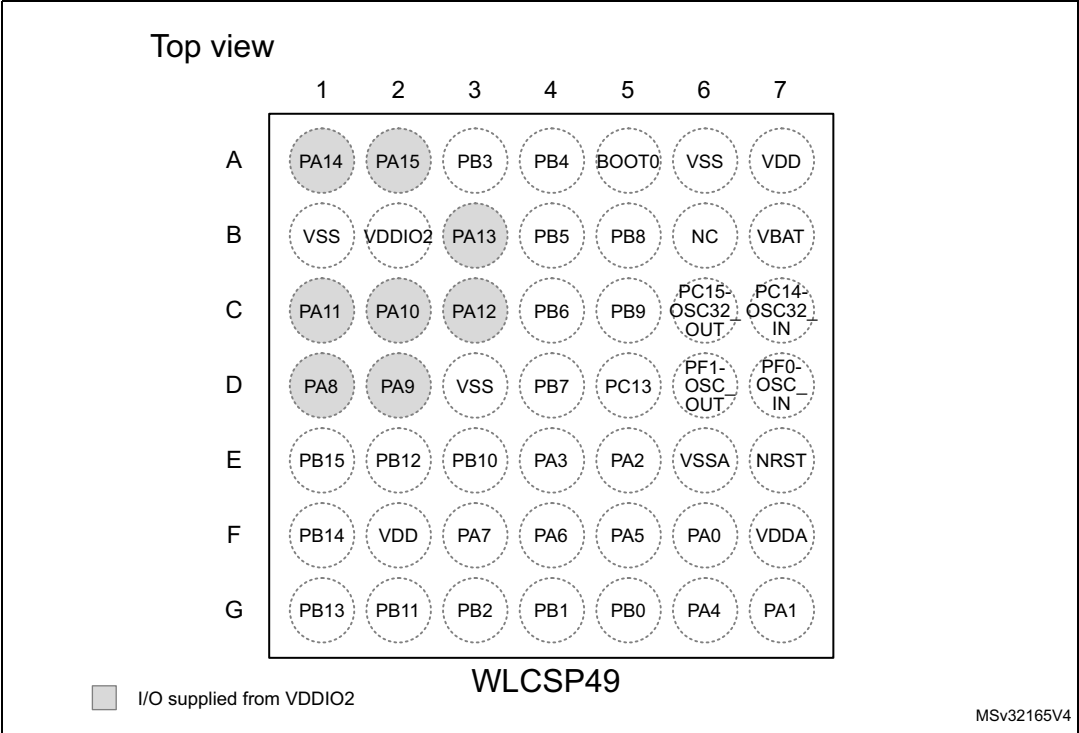


Figure 9. WLCSP49 package pinout



1. The above figure shows the package in top view, changing from bottom view in the previous document versions.



Table 15. Alternate functions selected through GPIOB_AFR registers for port B

Pin name	AF0	AF1	AF2	AF3	AF4	AF5
PB0	EVENTOUT	TIM3_CH3	TIM1_CH2N	TSC_G3_IO2	USART3_CK	-
PB1	TIM14_CH1	TIM3_CH4	TIM1_CH3N	TSC_G3_IO3	USART3_RTS	-
PB2	-	-	-	TSC_G3_IO4	-	-
PB3	SPI1_SCK, I2S1_CK	EVENTOUT	TIM2_CH2	TSC_G5_IO1	-	-
PB4	SPI1_MISO, I2S1_MCK	TIM3_CH1	EVENTOUT	TSC_G5_IO2	-	TIM17_BKIN
PB5	SPI1_MOSI, I2S1_SD	TIM3_CH2	TIM16_BKIN	I2C1_SMBA	-	-
PB6	USART1_TX	I2C1_SCL	TIM16_CH1N	TSC_G5_IO3	-	-
PB7	USART1_RX	I2C1_SDA	TIM17_CH1N	TSC_G5_IO4	USART4_CTS	-
PB8	CEC	I2C1_SCL	TIM16_CH1	TSC_SYNC	CAN_RX	-
PB9	IR_OUT	I2C1_SDA	TIM17_CH1	EVENTOUT	CAN_TX	SPI2_NSS, I2S2_WS
PB10	CEC	I2C2_SCL	TIM2_CH3	TSC_SYNC	USART3_TX	SPI2_SCK, I2S2_CK
PB11	EVENTOUT	I2C2_SDA	TIM2_CH4	TSC_G6_IO1	USART3_RX	-
PB12	SPI2_NSS, I2S2_WS	EVENTOUT	TIM1_BKIN	TSC_G6_IO2	USART3_CK	TIM15_BKIN
PB13	SPI2_SCK, I2S2_CK	-	TIM1_CH1N	TSC_G6_IO3	USART3_CTS	I2C2_SCL
PB14	SPI2_MISO, I2S2_MCK	TIM15_CH1	TIM1_CH2N	TSC_G6_IO4	USART3_RTS	I2C2_SDA
PB15	SPI2_MOSI, I2S2_SD	TIM15_CH2	TIM1_CH3N	TIM15_CH1N	-	-

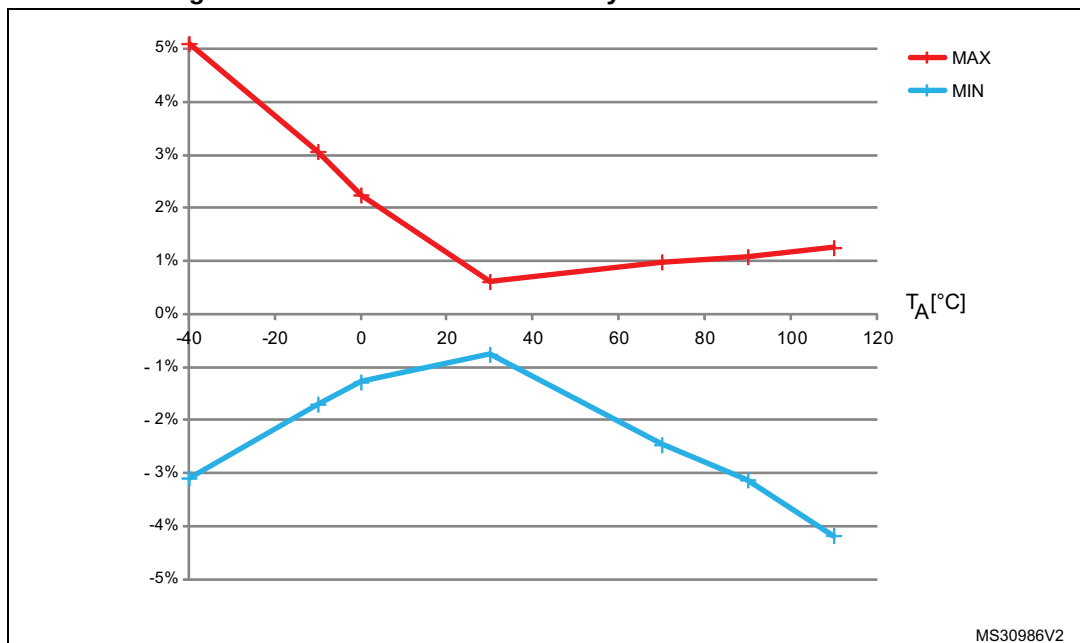
High-speed internal 14 MHz (HSI14) RC oscillator (dedicated to ADC)

Table 42. HSI14 oscillator characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSI14}	Frequency	-	-	14	-	MHz
TRIM	HSI14 user-trimming step	-	-	-	1 ⁽²⁾	%
DuCy _(HSI14)	Duty cycle	-	45 ⁽²⁾	-	55 ⁽²⁾	%
ACC _{HSI14}	Accuracy of the HSI14 oscillator (factory calibrated)	$T_A = -40$ to $105\text{ }^{\circ}\text{C}$	-4.2 ⁽³⁾	-	5.1 ⁽³⁾	%
		$T_A = -10$ to $85\text{ }^{\circ}\text{C}$	-3.2 ⁽³⁾	-	3.1 ⁽³⁾	%
		$T_A = 0$ to $70\text{ }^{\circ}\text{C}$	-2.5 ⁽³⁾	-	2.3 ⁽³⁾	%
		$T_A = 25\text{ }^{\circ}\text{C}$	-1	-	1	%
$t_{\text{su(HSI14)}}$	HSI14 oscillator startup time	-	1 ⁽²⁾	-	2 ⁽²⁾	μs
$I_{\text{DDA(HSI14)}}$	HSI14 oscillator power consumption	-	-	100	150 ⁽²⁾	μA

1. $V_{\text{DDA}} = 3.3\text{ V}$, $T_A = -40$ to $105\text{ }^{\circ}\text{C}$ unless otherwise specified.
2. Guaranteed by design, not tested in production.
3. Data based on characterization results, not tested in production.

Figure 20. HSI14 oscillator accuracy characterization results



High-speed internal 48 MHz (HSI48) RC oscillator

Table 43. HSI48 oscillator characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
f_{HSI48}	Frequency	-	-	48	-	MHz
TRIM	HSI48 user-trimming step	-	0.09 ⁽²⁾	0.14	0.2 ⁽²⁾	%
DuCy _(HSI48)	Duty cycle	-	45 ⁽²⁾	-	55 ⁽²⁾	%
ACC _{HSI48}	Accuracy of the HSI48 oscillator (factory calibrated)	$T_A = -40 \text{ to } 105 \text{ }^\circ\text{C}$	-4.9 ⁽³⁾	-	4.7 ⁽³⁾	%
		$T_A = -10 \text{ to } 85 \text{ }^\circ\text{C}$	-4.1 ⁽³⁾	-	3.7 ⁽³⁾	%
		$T_A = 0 \text{ to } 70 \text{ }^\circ\text{C}$	-3.8 ⁽³⁾	-	3.4 ⁽³⁾	%
		$T_A = 25 \text{ }^\circ\text{C}$	-2.8	-	2.9	%
$t_{\text{su(HSI48)}}$	HSI48 oscillator startup time	-	-	-	6 ⁽²⁾	μs
$I_{\text{DDA(HSI48)}}$	HSI48 oscillator power consumption	-	-	312	350 ⁽²⁾	μA

1. $V_{\text{DDA}} = 3.3 \text{ V}$, $T_A = -40 \text{ to } 105 \text{ }^\circ\text{C}$ unless otherwise specified.
2. Guaranteed by design, not tested in production.
3. Data based on characterization results, not tested in production.

Figure 21. HSI48 oscillator accuracy characterization results

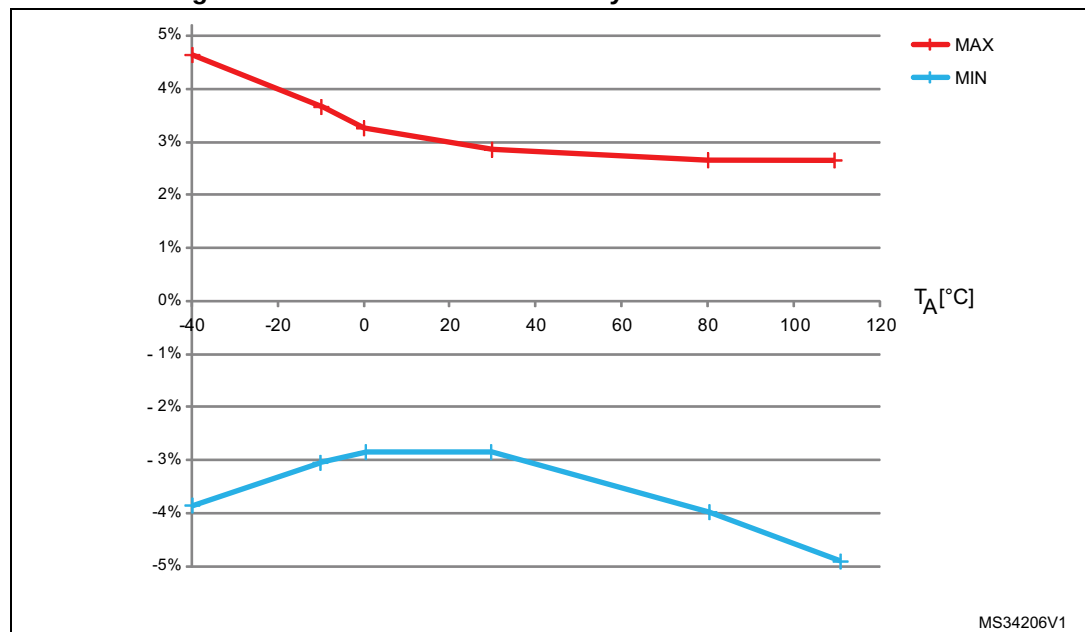
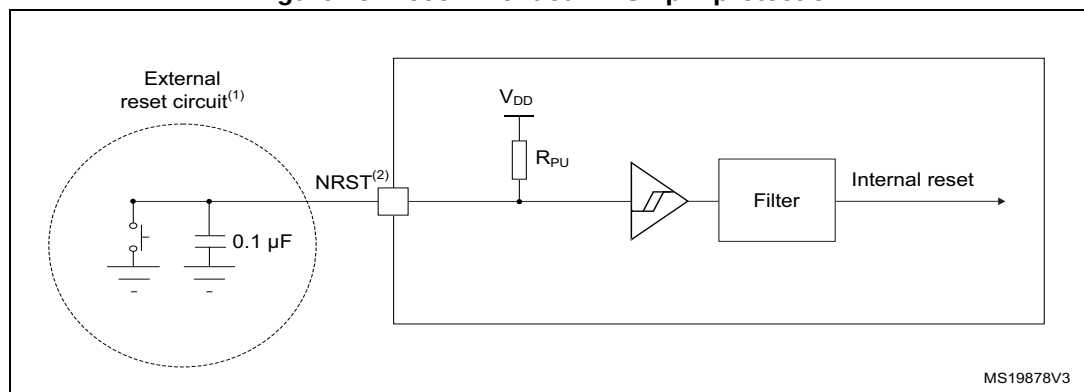


Table 56. NRST pin characteristics (continued)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{\text{hys(NRST)}}$	NRST Schmitt trigger voltage hysteresis	-	-	200	-	mV
R_{PU}	Weak pull-up equivalent resistor ⁽²⁾	$V_{\text{IN}} = V_{\text{SS}}$	25	40	55	k Ω
$V_{\text{F(NRST)}}$	NRST input filtered pulse	-	-	-	100 ⁽¹⁾	ns
$V_{\text{NF(NRST)}}$	NRST input not filtered pulse	$2.7 < V_{\text{DD}} < 3.6$	300 ⁽³⁾	-	-	ns
		$2.0 < V_{\text{DD}} < 3.6$	500 ⁽³⁾	-	-	

1. Data based on design simulation only. Not tested in production.
2. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimal (~10% order).
3. Data based on design simulation only. Not tested in production.

Figure 25. Recommended NRST pin protection



1. The external capacitor protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the $V_{\text{IL(NRST)}}$ max level specified in [Table 56: NRST pin characteristics](#). Otherwise the reset will not be taken into account by the device.

6.3.16 12-bit ADC characteristics

Unless otherwise specified, the parameters given in [Table 57](#) are derived from tests performed under the conditions summarized in [Table 24: General operating conditions](#).

Note: *It is recommended to perform a calibration after each power-up.*

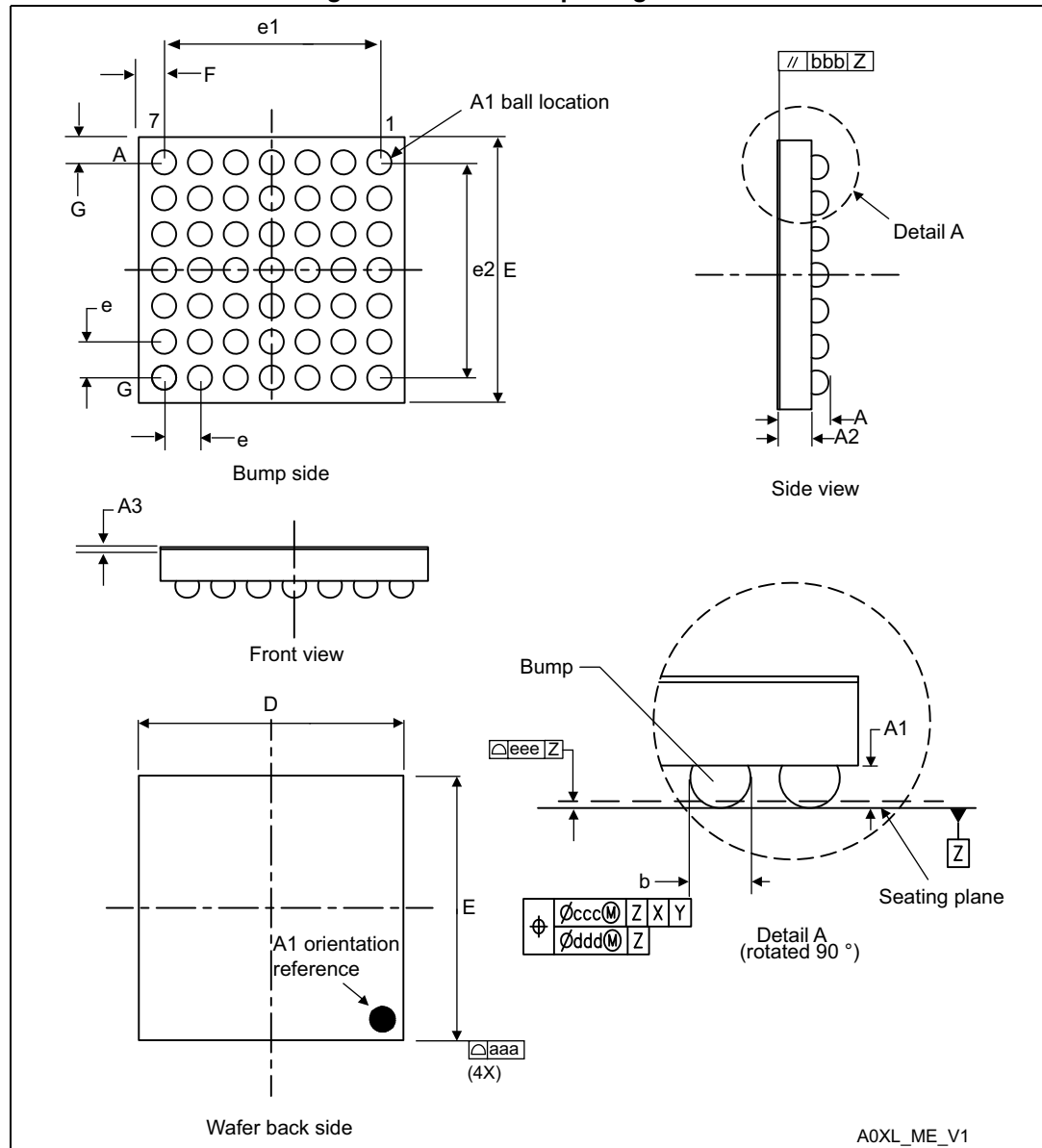
Table 57. ADC characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DDA}	Analog supply voltage for ADC ON	-	2.4	-	3.6	V
$I_{\text{DDA (ADC)}}$	Current consumption of the ADC ⁽¹⁾	$V_{\text{DDA}} = 3.3 \text{ V}$	-	0.9	-	mA
f_{ADC}	ADC clock frequency	-	0.6	-	14	MHz
$f_{\text{S}}^{(2)}$	Sampling rate	12-bit resolution	0.043	-	1	MHz

7.5 WLCSP49 package information

WLCSP49 is a 49-ball, 3.277 x 3.109 mm, 0.4 mm pitch wafer-level chip-scale package.

Figure 47. WLCSP49 package outline



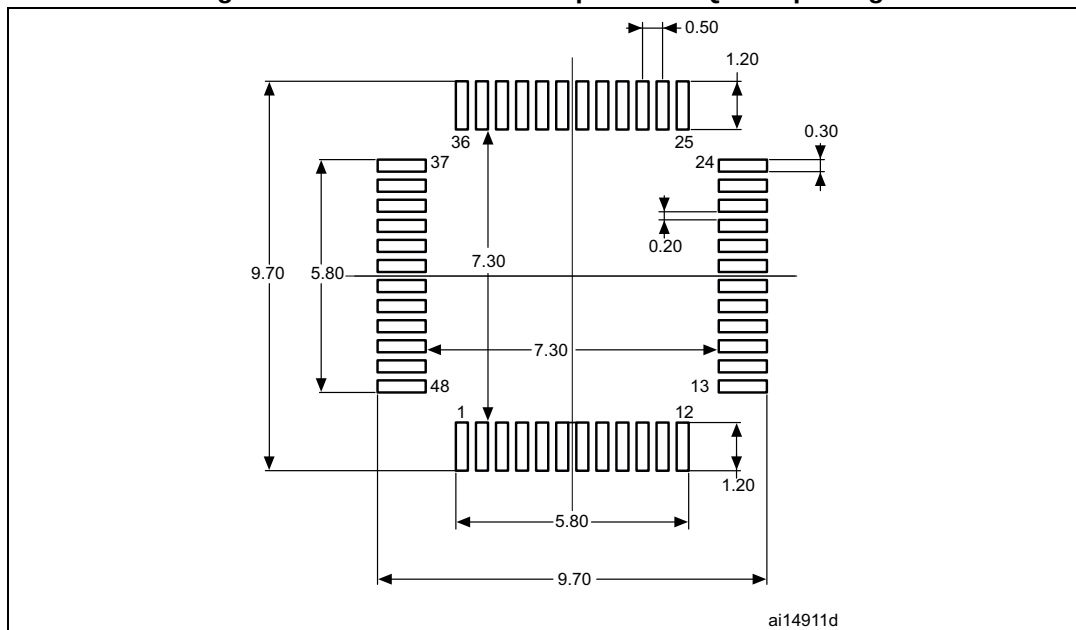
1. Drawing is not to scale.

Table 78. LQFP48 package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	-	-	1.600	-	-	0.0630
A1	0.050	-	0.150	0.0020	-	0.0059
A2	1.350	1.400	1.450	0.0531	0.0551	0.0571
b	0.170	0.220	0.270	0.0067	0.0087	0.0106
c	0.090	-	0.200	0.0035	-	0.0079
D	8.800	9.000	9.200	0.3465	0.3543	0.3622
D1	6.800	7.000	7.200	0.2677	0.2756	0.2835
D3	-	5.500	-	-	0.2165	-
E	8.800	9.000	9.200	0.3465	0.3543	0.3622
E1	6.800	7.000	7.200	0.2677	0.2756	0.2835
E3	-	5.500	-	-	0.2165	-
e	-	0.500	-	-	0.0197	-
L	0.450	0.600	0.750	0.0177	0.0236	0.0295
L1	-	1.000	-	-	0.0394	-
k	0°	3.5°	7°	0°	3.5°	7°
ccc	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 50. Recommended footprint for LQFP48 package



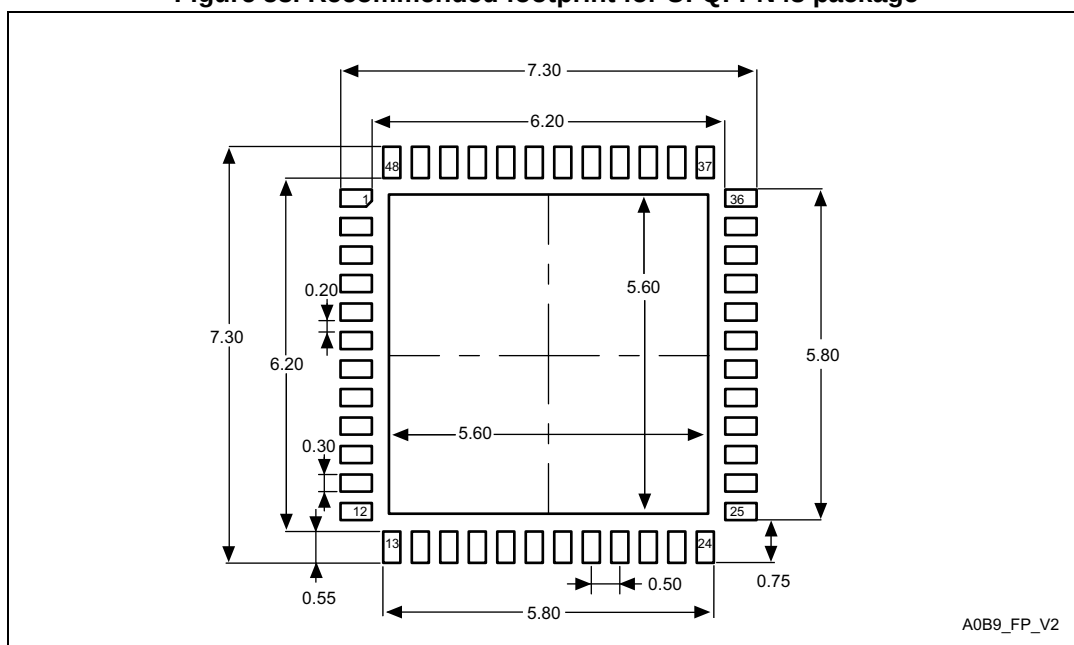
1. Dimensions are expressed in millimeters.

Table 79. UFQFPN48 package mechanical data

Symbol	millimeters			inches ⁽¹⁾		
	Min	Typ	Max	Min	Typ	Max
A	0.500	0.550	0.600	0.0197	0.0217	0.0236
A1	0.000	0.020	0.050	0.0000	0.0008	0.0020
D	6.900	7.000	7.100	0.2717	0.2756	0.2795
E	6.900	7.000	7.100	0.2717	0.2756	0.2795
D2	5.500	5.600	5.700	0.2165	0.2205	0.2244
E2	5.500	5.600	5.700	0.2165	0.2205	0.2244
L	0.300	0.400	0.500	0.0118	0.0157	0.0197
T	-	0.152	-	-	0.0060	-
b	0.200	0.250	0.300	0.0079	0.0098	0.0118
e	-	0.500	-	-	0.0197	-
ddd	-	-	0.080	-	-	0.0031

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 53. Recommended footprint for UFQFPN48 package



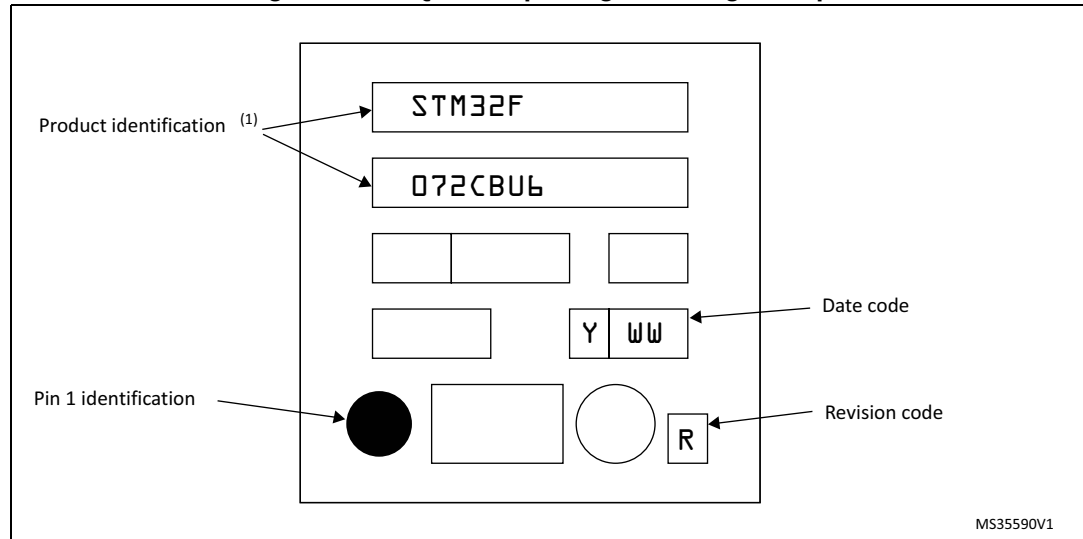
1. Dimensions are expressed in millimeters.

Device marking

The following figure gives an example of topside marking orientation versus pin 1 identifier location.

Other optional marking or inset/upset marks, which identify the parts throughout supply chain operations, are not indicated below.

Figure 54. UFQFPN48 package marking example



1. Parts marked as "ES", "E" or accompanied by an Engineering Sample notification letter, are not yet qualified and therefore not yet ready to be used in production and any consequences deriving from such usage will not be at ST charge. In no event, ST will be liable for any customer usage of these engineering samples in production. ST Quality has to be contacted prior to any decision to use these Engineering Samples to run qualification activity.

8 Ordering information

For a list of available options (memory, package, and so on) or for further information on any aspect of this device, please contact your nearest ST sales office.

Table 81. Ordering information scheme

Example:	STM32	F	072	R	8	T	6	x
Device family STM32 = ARM-based 32-bit microcontroller								
Product type F = General-purpose								
Sub-family 072 = STM32F072xx								
Pin count C = 48/49 pins R = 64 pins V = 100 pins								
User code memory size 8 = 64 Kbyte B = 128 Kbyte								
Package H = UFBGA T = LQFP U = UFQFPN Y = WLCSP								
Temperature range 6 = -40 to 85 °C 7 = -40 to 105 °C								
Options xxx = code ID of programmed parts (includes packing type) TR = tape and reel packing blank = tray packing								

Table 82. Document revision history (continued)

Date	Revision	Changes
18-Sep-2015	3 (continued)	– Table 42: HSI14 oscillator characteristics: changed the min value for ACC_{HSI14} – Table 46: Flash memory characteristics: removed V_{prog} – Table 49: EMI characteristics updated – Table 50: ESD absolute maximum ratings updated – Table 57: ADC characteristics - updated some parameter values, test conditions and added footnotes ⁽³⁾ and ⁽⁴⁾ – Table 60: DAC characteristics - I_{DDA} max value (DAC DC current consumption) updated – Table 61: Comparator characteristics: changed the description and values for t_{S_SC} parameter – Table 62: TS characteristics: changed the min value for t_{S_temp} – Table 63: VBAT monitoring characteristics: changed the typical value for R parameter – Table 69: I²S characteristics: updated the min value for data input hold time (master and slave receiver) Section 7: Package information: – information generally updated, UFBGA64 added Section 8: Part numbering: UFBGA64 added
17-Dec-2015	4	Section 2: Description: – Figure 1: Block diagram updated Section 3: Functional overview: – Figure 2: Clock tree updated Section 4: Pinouts and pin descriptions – Package pinout figures updated (look and feel) – Figure 9: WLCSP49 package pinout - now presented in top view Section 5: Memory mapping: – added information on STM32F072x8 difference versus STM32F072xB map in Figure 10 – Table 28: Embedded internal reference voltage: removed -40°-to-85° condition for V_{REFINT} and associated note Section 6: Electrical characteristics: – Table 61: Comparator characteristics - min value for V_{DDA} replaced with V_{DD} – Figure 29: Maximum V_{REFINT} scaler startup time from power down added – Table 53: I/O static characteristics - note removed – Table 69: I²S characteristics: table reorganized Section 8: Ordering information: – added tray packing to options

Table 82. Document revision history (continued)

Date	Revision	Changes
10-Jan-2017	5	Section 6: Electrical characteristics: – <i>Table 40: LSE oscillator characteristics ($f_{LSE} = 32.768$ kHz)</i> - information on configuring different drive capabilities removed. See the corresponding reference manual. – <i>Table 28: Embedded internal reference voltage</i> - V_{REFINT} values – <i>Table 60: DAC characteristics</i> - min. R_{LOAD} to V_{DDA} defined – <i>Figure 30: SPI timing diagram - slave mode and CPHA = 0</i> and <i>Figure 31: SPI timing diagram - slave mode and CPHA = 1</i> enhanced and corrected Section 8: Ordering information: – The name of the section changed from the previous “Part numbering”